

I. Electrostatic Field Flux- Gauss's Law:

Representation of a surface:

An elementary surface (dS) is represented by a vector $d\vec{S}$ perpendicular to this surface and whose modulus is equal to the area of this surface.

 $d\vec{S} = dS\vec{u}$

With $|\vec{u}| = 1$



 \Box For a closed surface, The vector \overrightarrow{dS} is oriented outward..

Solid Angles

A solid angle is the space included inside a conical (or pyramidal) surface.

□ Its value, expressed in *steradians* (sr), is obtained by drawing, with arbitrary radius *R* and center at the vertex *O*, a spherical surface and applying the relation: $\Omega = \frac{S}{R^2}$



□ Since the surface area of a sphere is $4\pi R^2$, we conclude that the complete solid angle around a point is: $4\pi R^2$

$$\Omega = \frac{4\pi R^2}{R^2} = 4\pi$$



□ When the solid angle is small, Then:



 \Box In some cases the surface *dS* is not perpendicular to \overrightarrow{OP} , it makes an angle θ with *OP*.

Then it is necessary to project *dS* on a plane perpendicular to *OP*, which gives us the area: $dS' = dS \cos \theta$

Thus:
$$d\Omega = \frac{dS \cos \theta}{R^2}$$



<u>Gauss's law:</u>

Flux of the Electrostatic Field:

Let a closed surface (S) inside which there is a charge q.



The flux of the electrostatic field (\vec{E}) through the surface *dS* is:

$$d\phi = \vec{E}.d\vec{S}$$

The total flow of \vec{E} across the surface S is therefore:

$$\phi = \oint d\phi = \oint_{(S)} \vec{E} \cdot d\vec{S}$$

Gauss's theorem:

A simple example allows us to find Gauss's theorem:

- ✓ Let a positive charge q_i .
- ✓ We choose an "imaginary" spherical surface (S) centered on q_i and having a radius r.

The elementary flux $d\phi$ of the field \vec{E} Created by q_i and passing

through the surface dS is given by: $d\phi = \vec{E} \cdot d\vec{S} \left(\vec{E} / / \vec{dS} \right)$

The total flow ϕ of \overrightarrow{E} across the surface (S) is therefore:

$$\phi = \oint d\phi = \oint_{(S)} \vec{E} \cdot d\vec{S} = \oint_{(S)} \frac{kq_i}{r^2} \cdot dS = \frac{q_i}{4\pi\varepsilon_0 r^2} \oint_0^{4\pi r^2} dS = \frac{q_i}{\varepsilon_0}$$

r

 q_i

Consider now a charge q inside an arbitrary closed surface S

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We have
$$: d\phi = \vec{E} \cdot d\vec{S}$$

 $\phi = \oint d\phi = \oint_{(S)} \vec{E} \cdot d\vec{S} = \oint_{(S)} \vec{E} \cdot dS \cos \theta$
 $= \oint_{(S)} \frac{kq_i}{r^2} \cdot dS \cdot \cos \theta = \frac{q_i}{4\pi\varepsilon_0} \oint_{(S)} \frac{dS \cos \theta}{r^2}$

 $\frac{d\sigma}{r^2} = d\Omega$: solid angle subtended by the surface element dS as viewed from the charge q

Since the total solid angle around any point is 4π steradians. Then:

$$\phi = \frac{q_i}{4\pi\varepsilon_0} \int_0^{4\pi} d\Omega = \frac{q_i}{\varepsilon_0}$$

<u>Theorem</u>: The Flow of the Field \vec{E} through a closed surface surrounding charges q_i is :

$$\phi = \oint_{(S)} \vec{E} \cdot d\vec{S} = \frac{\sum q_i}{\varepsilon_0}$$

Method of applying Gauss's theorem:

Gauss's theorem provides a very useful method for calculating the field \vec{E} when it has particular symmetry properties.

- Find a closed surface passing through the point "M" where we want to calculate the field. The chosen surface must be composed of parts where:
 - Let the field be null
 - Let the field be constant in modulus and equal to E_M and parallel to dS
 - Let the field be perpendicular to *dS*
 - 2. Write the definition of the flow $\phi = \bigoplus_{(S)} \vec{E} \cdot d\vec{S}$
 - 3. Apply Gaussian's theorem after counting the algebraic charge inside the surface.

Applications

Example 1: Determine the expression of the field created by a punctual charge **q** at a

point **M** in space at a distance **r** from the charge **q**.

- □ The problem has spherical symmetry,
- \Box The field is radial $\vec{E}(M) = E(M)\vec{u}_r$,
- The surface of Gauss (S) to chosed is a sphere with center
 O and radius r.
- □ At each point of (S) the field is:
 - ✓ Perpendicular to (S)
 - ✓ Constant in modulus

$$\phi = \oint_{(S)} \vec{E}(M) \cdot d\vec{S} = E(M) \oint_{(S)} ds = E(M) \cdot S = E(M) \cdot 4\pi r^2 = \frac{\sum q_i}{\varepsilon_0} = \frac{q}{\varepsilon_0}$$
$$\implies E(M) = \frac{q}{1 - \frac{q}{\varepsilon_0}}$$



Example 2: Determine the expression of the field created by a charge distributed uniformly

on an infinite straight wire with a constant linear density $\lambda > 0$

 \Box The field \vec{E} is radial and is perpendicular to the wire at any point M of space:

 $\vec{E}(M) = E(M)\vec{u}_r$

□ The problem has cylindrical symmetry

□ The chosen Gaussian surface (S) is a closed cylinder of radius r and length L.

 \Box The surface (S) consists of the 3 surfaces: S_1, S_2, S_3

✓
$$S_1$$
: represent by $d\vec{S}_1$ with $d\vec{E}//d\vec{S}_1$
✓ S_2 : represent by $d\vec{S}_2$ with $d\vec{E} \perp d\vec{S}_2$
✓ S_3 : represent by $d\vec{S}_3$ with $d\vec{E} \perp d\vec{S}_3$
 $\phi = \iint_{(S)} \vec{E}(M). d\vec{S} = \oiint_{(S)} \vec{E}(M). d\vec{S}_1 + \oiint_{(S)} \vec{E}(M). d\vec{S}_2 + \oiint_{(S)} \vec{E}(M). d\vec{S}_3$



$$\Rightarrow \phi = \oint_{(S)} E(M) \cdot dS_1 = E(M) \oint_{(S)} dS_1 = E(M) 2\pi rL = \frac{\sum q_i}{\varepsilon_0} = \frac{\lambda L}{\varepsilon_0}$$
$$\Rightarrow E(M) = \frac{\lambda}{2\pi r\varepsilon_0}$$

From this, we can deduce the expression of the potential from the relation:

$$\vec{E} = -\overline{grad}V \Longrightarrow E_r \vec{u}_r + E_\theta \vec{u}_\theta + E_z \vec{u}_z = -\frac{\partial V}{\partial r} \vec{u}_r - \frac{1}{r} \frac{\partial V}{\partial \theta} \vec{u}_\theta - \frac{\partial V}{\partial z} \vec{u}_z$$
$$\implies E_r = -\frac{\partial V}{\partial r} \implies dV = -Edr = -\frac{\lambda}{2\pi r \varepsilon_0} dr$$
$$\implies V(M) = -\frac{\lambda}{2\pi \varepsilon_0} \int \frac{dr}{r} = -\frac{\lambda}{2\pi \varepsilon_0} \ln r + Cte$$

Example 3: Determine the electric field created by a uniform surface charge distribution

on an infinite plane with a surface density $\sigma > 0$

- $\Box \vec{E}$ is perpendicular to the plane
- $\square \vec{E} \text{ is uniform on both sides of the plane but}$ the direction changes: $\vec{E}_1 = -\vec{E}_2$
- We take as the Gaussian surface a cylinder of height h and base area S, symmetrical with respect to the plane.



Λ

The surface (S) consists of the 3 surfaces represented by $\overrightarrow{dS}_1, \overrightarrow{dS}_2, \overrightarrow{dS}_3$

$$\phi = \oint_{(S)} \vec{E}(M) \cdot d\vec{S} = \oint_{(S)} \vec{E}(M) \cdot d\vec{S}_1 + \oint_{(S)} \vec{E}(M) \cdot d\vec{S}_2 + \oint_{(S)} \vec{E}(M) \cdot d\vec{S}_3 = \frac{\sum q_{\vec{E}}}{\varepsilon_0}$$
$$\Rightarrow \phi = 2E(M) \oint_{(S)} dS = 2E(M) \cdot S = \frac{\sigma S}{\varepsilon_0} \Rightarrow E(M) = \frac{\sigma}{2\varepsilon_0}$$

Example 4:

Let be a solid ball with center O and radius R uniformly charged by volume (with charge density ρ). Calculate the electrostatic field created by this ball inside, on the surface, and outside the ball.

□ We take, as a Gaussian surface, a sphere with center O and radius r.

$$\phi = \oint_{(S)} \vec{E}(M) \cdot d\vec{S} = \frac{\sum q_i}{\varepsilon_0} \Longrightarrow E(M) \cdot 4\pi r^2 = \frac{\rho V_i}{\varepsilon_0}$$

□ Inside the ball:

$$\checkmark r < R: \qquad \sum q_i = \rho \frac{4}{3} \pi r^3 \implies E(M) = \frac{\rho r}{3\varepsilon_0}$$



□ On the surface and outside of the ball:

$$\checkmark r \ge R: \quad \sum q_i = \rho \frac{4}{3} \pi R^3 \implies E(M) = \frac{\rho R^3}{3\varepsilon_0 r^2}$$